

# SOT-563 中的 INA185 超小型、双向、精密低侧和高侧电压输出 电流检测放大器

## 1 特性

- SOT-563 封装 (1.6mm × 1.6mm)
  - 尺寸比 SC70 小 39%
  - 0.55mm 封装高度
- 共模范围 ( $V_{CM}$ ): -0.2V 至 +26V
- 高带宽: 350kHz (A1 器件)
- 失调电压:
  - $\pm 55\mu\text{V}$  (最大值),  $V_{CM} = 0\text{V}$
  - $\pm 100\mu\text{V}$  (最大值),  $V_{CM} = 12\text{V}$  (A4 器件)
- 输出压摆率: 2V/ $\mu\text{s}$
- 双向电流检测功能
- 精度:
  - 最大增益误差:  $\pm 0.2\%$  (A1、A2、A3)
  - 最大温漂: 0.5- $\mu\text{V}/^\circ\text{C}$
- 增益选项:
  - 20V/V (A1 器件)
  - 50V/V (A2 器件)
  - 100V/V (A3 器件)
  - 200V/V (A4 器件)
- 瞬态电流: 260 $\mu\text{A}$  (最大值)

## 2 应用

- 电机控制
- 电池监控
- 电源管理
- 照明控制
- 过流检测
- 光伏逆变器

## 3 说明

INA185 电流检测放大器专为成本敏感、空间受限的应用而设计。此器件是一个双向电流检测放大器（也称为电流分流监控器），可在独立于电源电压的 -0.2V 至 +26V 范围内的共模电压中感测电流检测电阻器上的压降。INA185 以四个固定增益器件选项集成匹配电阻器增益网络：20V/V、50V/V、100V/V 或 200和V/V。该匹配增益电阻器网络可最大限度地减小增益误差并降低温度漂移。

INA185 由 2.7V 至 5.5V 单电源供电。它消耗的最大电源电流为 260 $\mu\text{A}$ ，拥有高压摆率和带宽，因此是许多电源和电机控制解决方案的理想选择。

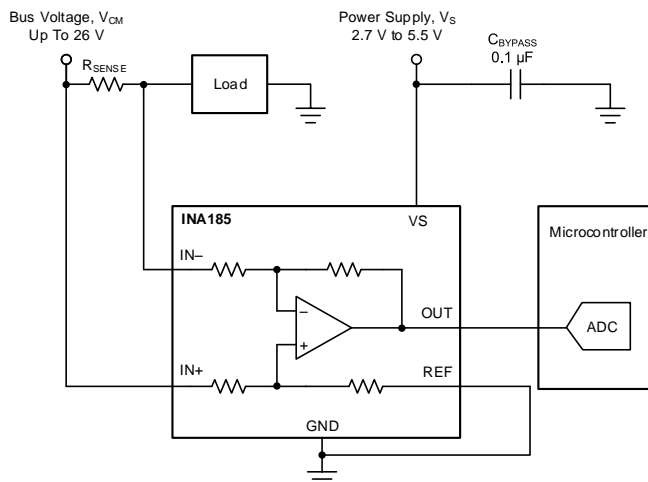
INA185 采用 6 引脚 SOT-563 封装，包括器件引脚在内的外形面积仅为 2.56 mm<sup>2</sup>。所有器件选项都具有 -40 $^\circ\text{C}$  至 +125 $^\circ\text{C}$  的扩展额定工作温度范围。

器件信息<sup>(1)</sup>

器件型号	封装	封装尺寸 (标称值)
INA185	SOT-563 (6)	1.60mm × 1.60mm (包括引脚)

(1) 如需了解所有可用封装，请参阅数据表末尾的封装选项附录。

典型应用电路



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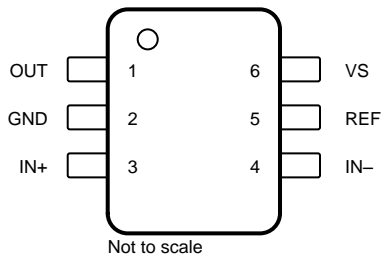
## 4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

日期	修订版本	说明
2019 年 3 月	*	初始发行版。

## 5 Pin Configuration and Functions

**INA185: DRL Package  
6-Pin SOT-563  
Top View**



**Pin Functions**

PIN		TYPE	DESCRIPTION
NAME	NO.		
GND	2	Analog	Ground
IN-	4	Analog input	Current-sense amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.
IN+	3	Analog input	Current-sense amplifier positive input. For high-side applications, connect to bus-voltage side of sense resistor. For low-side applications, connect to load side of sense resistor.
OUT	1	Analog output	Output voltage
REF	5	Analog input	Reference input
VS	6	Analog	Power supply, 2.7 V to 5.5 V

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
$V_S$	Supply voltage		6	V
	Analog inputs, IN+, IN- <sup>(2)</sup>	Differential ( $V_{IN+} - V_{IN-}$ )	-26	26
		Common-mode <sup>(3)</sup>	GND - 0.3	26
$V_{REF}$	Reference voltage	GND - 0.3	$V_S + 0.3$	V
$V_{OUT}$	Output voltage <sup>(3)</sup>	GND - 0.3	$V_S + 0.3$	V
$T_A$	Operating temperature	-55	150	°C
$T_J$	Junction temperature		150	°C
$T_{stg}$	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2)  $V_{IN+}$  and  $V_{IN-}$  are the voltages at the IN+ and IN- pins, respectively.

(3) Input voltage at any pin can exceed the voltage shown if the current at that pin is limited to 5 mA.

### 6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±3000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$V_{CM}$	Common-mode input voltage	-0.2	12	26	V
$V_S$	Operating supply voltage	2.7	5	5.5	V
$T_A$	Operating free-air temperature	-40		125	°C

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		INA185	UNIT
		DRL (SOT-563)	
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	230.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	94.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	112.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	3.8	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	112.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application report](#).

## 6.5 Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_{\text{SENSE}} = V_{\text{IN}+} - V_{\text{IN}-}$ ,  $V_S = 5\text{ V}$ ,  $V_{\text{REF}} = V_S / 2$ , and  $V_{\text{IN}+} = 12\text{ V}$  (unless otherwise noted)

PARAMETER		CONDITIONS		MIN	TYP	MAX	UNIT
<b>INPUT</b>							
CMRR	Common-mode rejection ratio, RTI <sup>(1)</sup>	$V_{\text{IN}+} = 0\text{ V to } 26\text{ V}$ , $V_{\text{SENSE}} = 0\text{ mV}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$	A1 device	86	100		dB
			A2, A3 devices	96	100		
			A4 devices	106	120		
$V_{\text{OS}}$	Offset voltage, RTI	$V_{\text{SENSE}} = 0\text{ mV}$ , $V_{\text{IN}+} = 0\text{ V}$	A1 devices		$\pm 25$	$\pm 135$	$\mu\text{V}$
			A2, A3, A4 devices		$\pm 5$	$\pm 55$	
		$V_{\text{SENSE}} = 0\text{ mV}$ , $V_{\text{IN}+} = 12\text{ V}$	A1 devices		$\pm 100$	$\pm 450$	
			A2, A3 devices		$\pm 25$	$\pm 130$	
			A4 device		$\pm 25$	$\pm 100$	
$dV_{\text{OS}}/dT$	Offset drift, RTI	$V_{\text{SENSE}} = 0\text{ mV}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$		0.2	0.5	$\mu\text{V}/^\circ\text{C}$	
PSRR	Power supply rejection ratio, RTI	$V_S = 2.7\text{ V to } 5.5\text{ V}$ , $V_{\text{IN}+} = 12\text{ V}$ , $V_{\text{SENSE}} = 0\text{ mV}$		$\pm 8$	$\pm 30$	$\mu\text{V}/\text{V}$	
$I_{\text{IB}}$	Input bias current	$V_{\text{SENSE}} = 0\text{ mV}$ , $V_{\text{CM}} = 0\text{ V}$			-6		$\mu\text{A}$
		$V_{\text{SENSE}} = 0\text{ mV}$			75		
$I_{\text{IO}}$	Input offset current	$V_{\text{SENSE}} = 0\text{ mV}$			$\pm 0.05$		$\mu\text{A}$
<b>OUTPUT</b>							
G	Gain		A1 devices		20		V/V
			A2 devices		50		
			A3 devices		100		
			A4 devices		200		
$E_G$	Gain error	$V_{\text{OUT}} = 0.5\text{ V to } V_S - 0.5\text{ V}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$	A1, A2, A3 devices		$\pm 0.05\%$	$\pm 0.2\%$	
			A4 device		$\pm 0.07\%$	$\pm 0.25\%$	
	Gain error drift	$T_A = -40^\circ\text{C to } +125^\circ\text{C}$			1.5	8	ppm/ $^\circ\text{C}$
	Nonlinearity error	$V_{\text{OUT}} = 0.5\text{ V to } V_S - 0.5\text{ V}$			$\pm 0.01\%$		
	Maximum capacitive load	No sustained oscillation			1		nF
<b>VOLTAGE OUTPUT <sup>(2)</sup></b>							
$V_{\text{SP}}$	Swing to $V_S$	$R_L = 10\text{ k}\Omega$ to GND, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$			$(V+) - 0.02$	$(V+) - 0.026$	V
$V_{\text{SN}}$	Swing to GND	$R_L = 10\text{ k}\Omega$ to GND, $V_{\text{IN}+} - V_{\text{IN}-} = -10\text{ mV}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$			$(V_{\text{GND}}) + 0.0005$	$(V_{\text{GND}}) + 0.0035$	V
$V_{\text{SG}}$	Zero current swing to GND	$R_L = \text{Open}$ , $V_{\text{IN}+} - V_{\text{IN}-} = 0\text{ mV}$ , $V_{\text{REF}} = 0\text{ V}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$	A1 devices		$(V_{\text{GND}}) + 0.0005$	$(V_{\text{GND}}) + 0.006$	V
			A2, A3, A4 devices		$(V_{\text{GND}}) + 0.0005$	$(V_{\text{GND}}) + 0.012$	
<b>FREQUENCY RESPONSE</b>							
BW	Bandwidth	$C_{\text{LOAD}} = 10\text{ pF}$	A1 devices		350		kHz
			A2 devices		210		
			A3 devices		150		
			A4 devices		105		
SR	Slew rate				2		V/ $\mu\text{s}$
<b>NOISE, RTI <sup>(1)</sup></b>							
	Voltage noise density				40		nV/ $\sqrt{\text{Hz}}$
<b>POWER SUPPLY</b>							
$I_Q$	Quiescent current	$V_{\text{SENSE}} = 0\text{ mV}$			200	260	$\mu\text{A}$
		$V_{\text{SENSE}} = 0\text{ mV}$ , $T_A = -40^\circ\text{C to } +125^\circ\text{C}$					

(1) RTI = referred-to-input.

(2) See Typical Characteristic curve, *Output Voltage Swing vs Output Current* (图 19).

## 6.6 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{\text{REF}} = V_S / 2$ , and  $V_{\text{IN}+} = 12\text{ V}$  (unless otherwise noted)

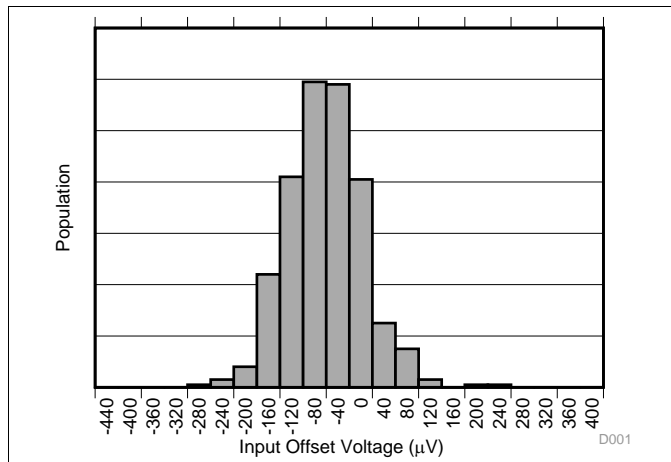


图 1. Input Offset Voltage Production Distribution A1

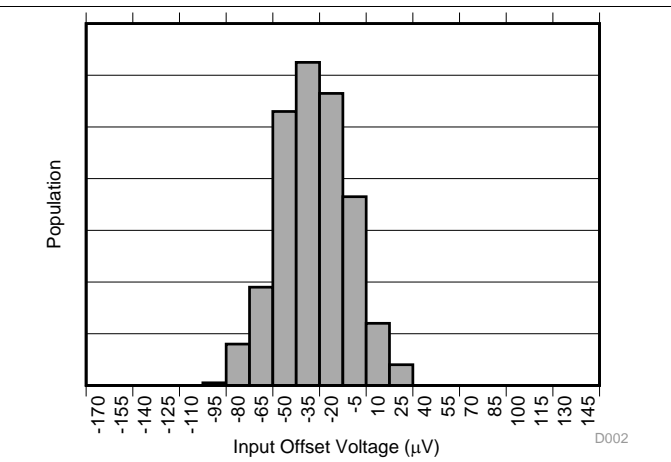


图 2. Input Offset Voltage Production Distribution A2

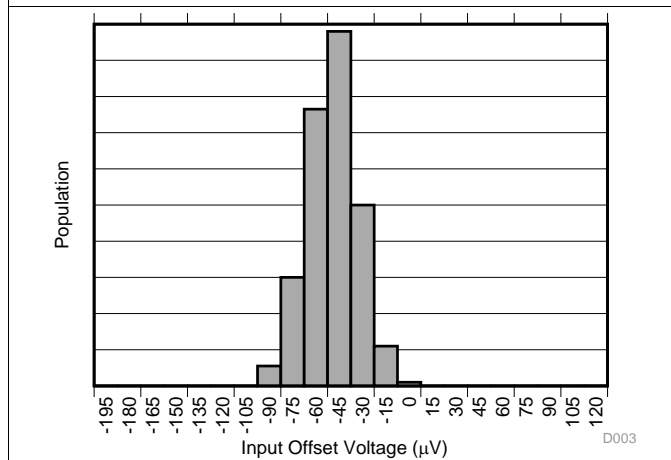


图 3. Input Offset Voltage Production Distribution A3

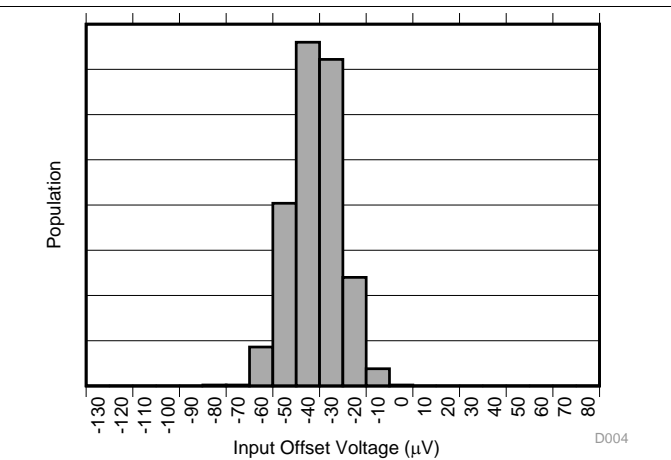


图 4. Input Offset Voltage Production Distribution A4

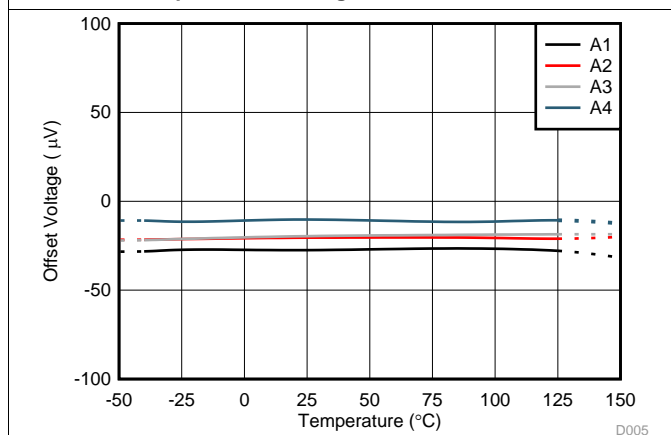


图 5. Offset Voltage vs Temperature

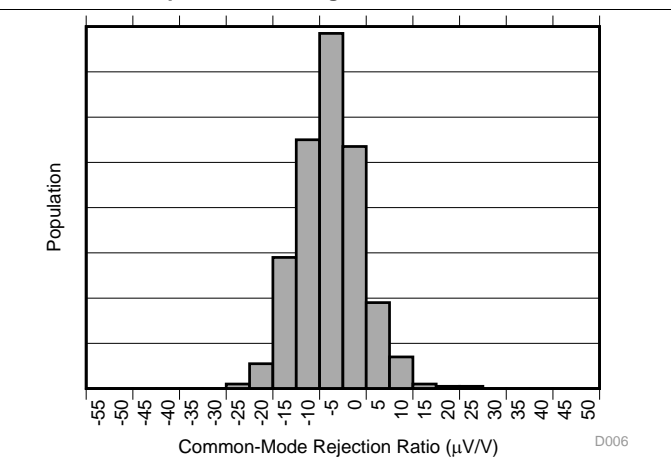
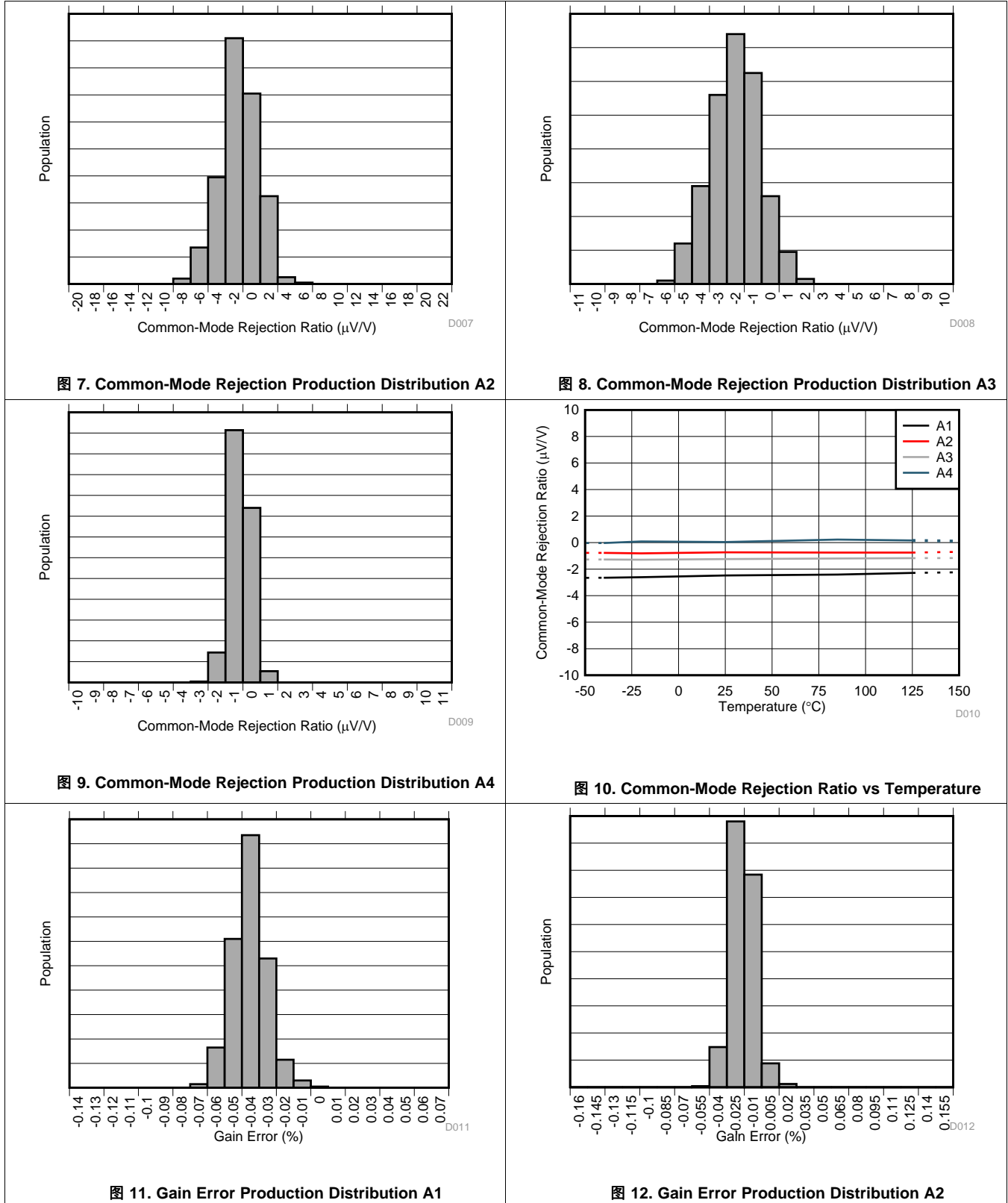


图 6. Common-Mode Rejection Production Distribution A1

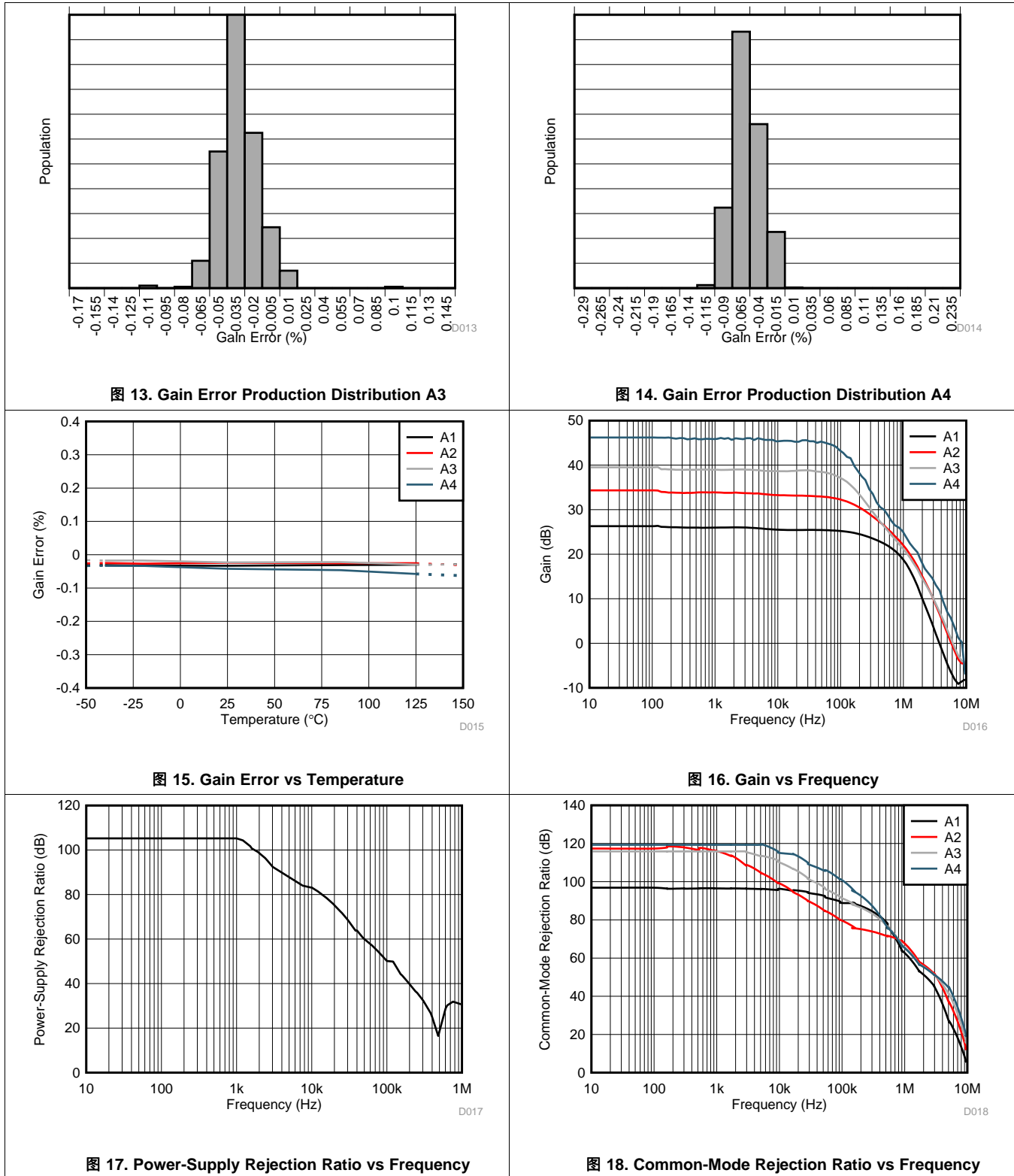
Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{REF} = V_S / 2$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)



Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{REF} = V_S / 2$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)





Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{\text{REF}} = V_S / 2$ , and  $V_{\text{IN}+} = 12\text{ V}$  (unless otherwise noted)

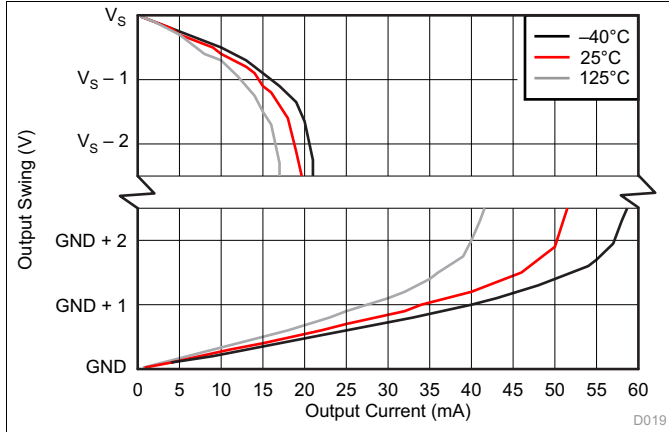


图 19. Output Voltage Swing vs Output Current

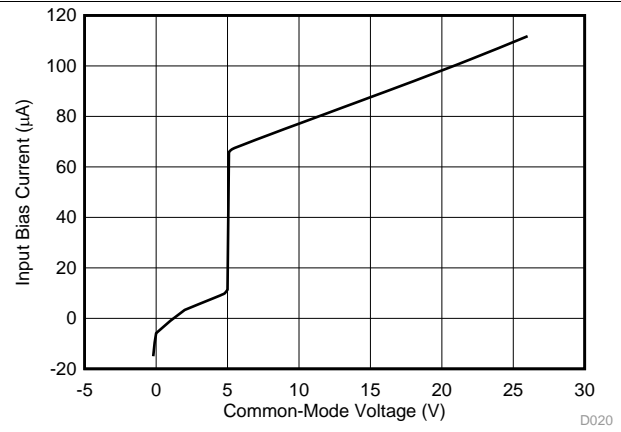


图 20. Input Bias Current vs Common-Mode Voltage

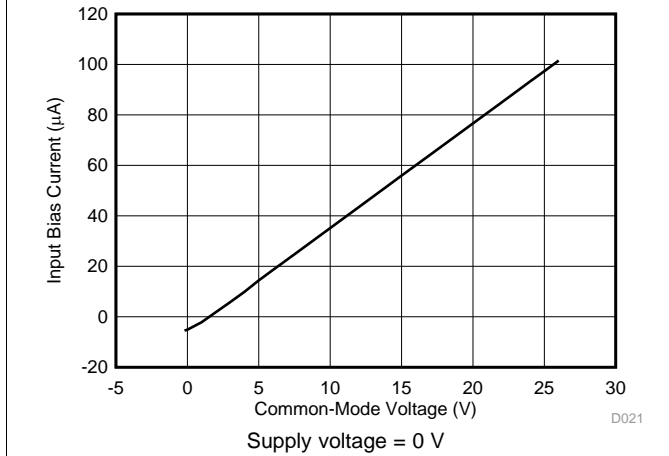


图 21. Input Bias Current vs Common-Mode Voltage (Both Inputs, Shutdown)

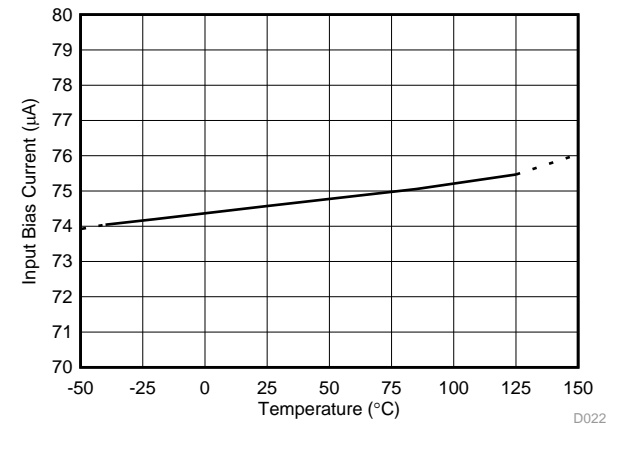


图 22. Input Bias Current vs Temperature

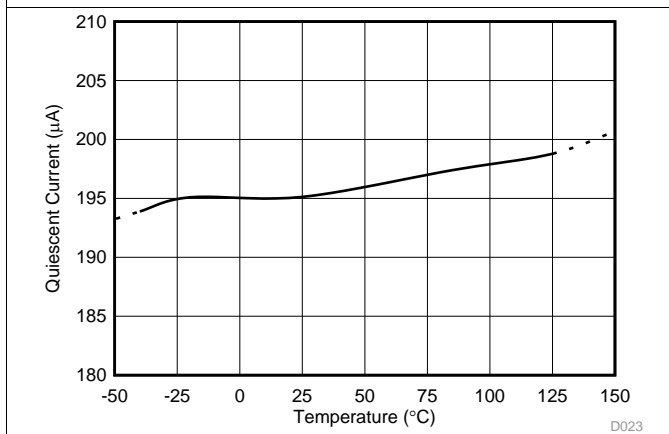


图 23. Quiescent Current vs Temperature

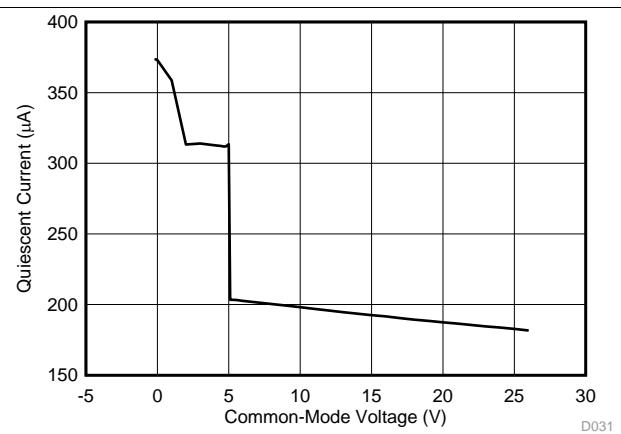


图 24.  $I_Q$  vs Common-Mode Voltage

Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{\text{REF}} = V_S / 2$ , and  $V_{\text{IN}+} = 12\text{ V}$  (unless otherwise noted)

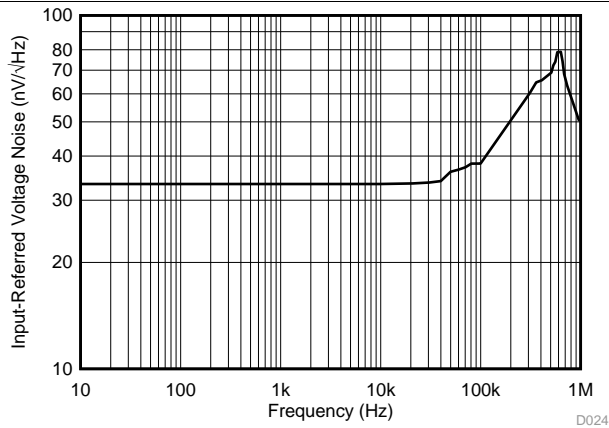


图 25. Input-Referred Voltage Noise vs Frequency (A3 Devices)

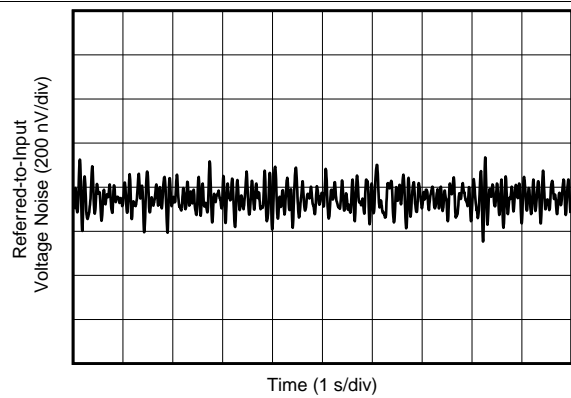
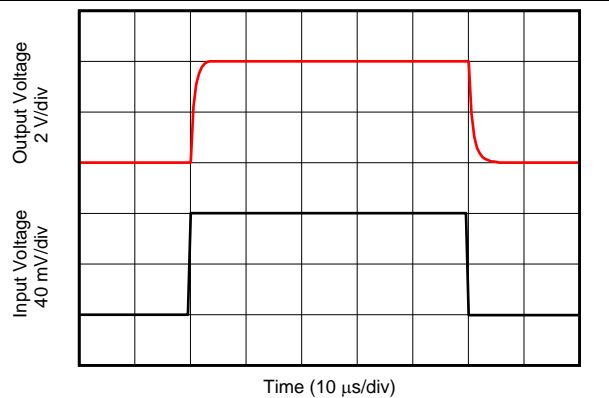


图 26. 0.1-Hz to 10-Hz Voltage Noise (Referred-to-Input)



80-mV<sub>PP</sub> input step

图 27. Step Response

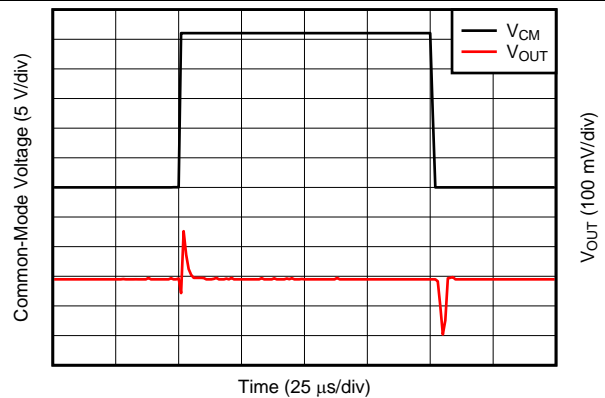


图 28. Common-Mode Voltage Transient Response

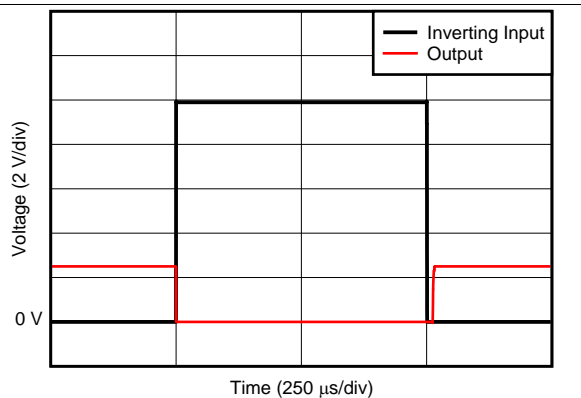


图 29. Inverting Differential Input Overload

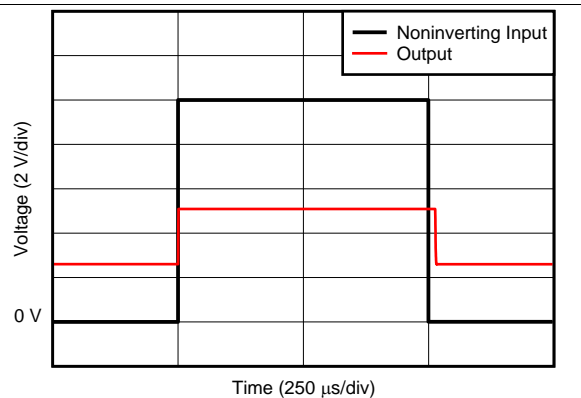
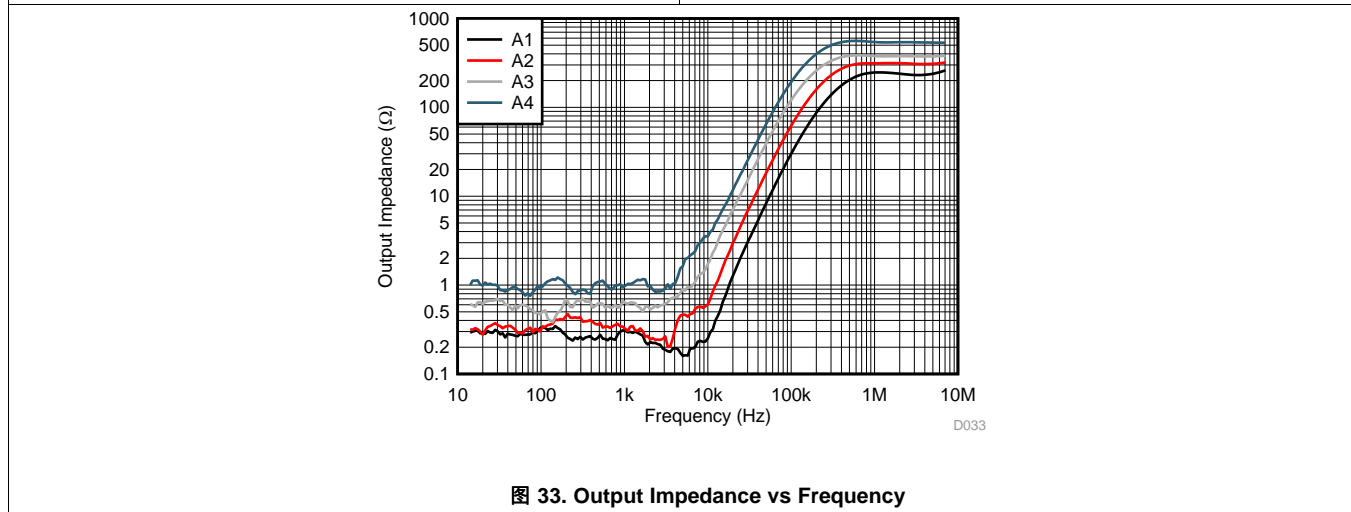
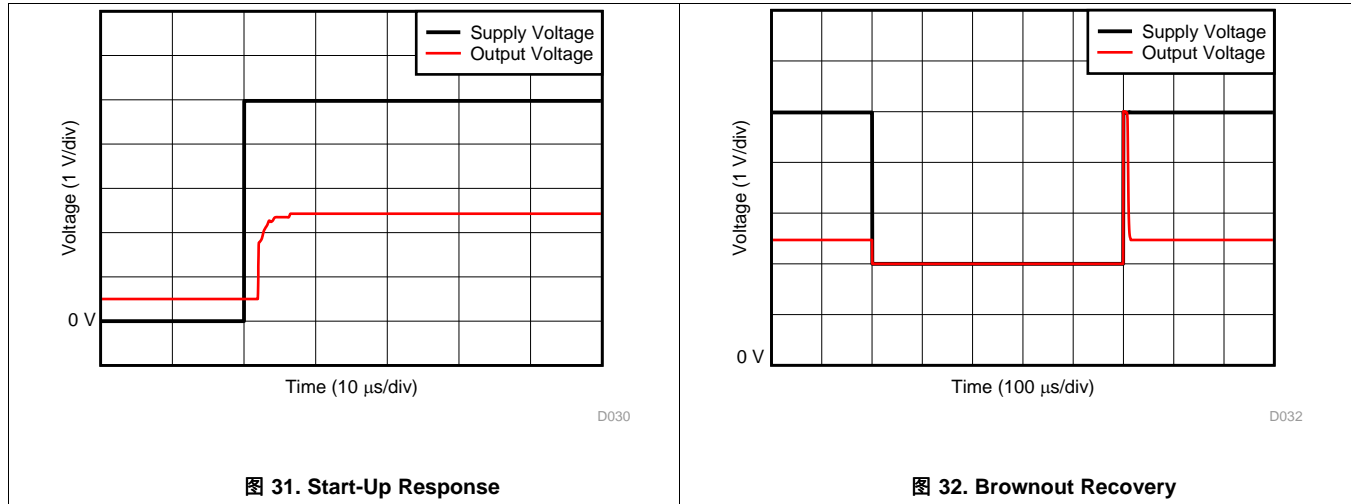


图 30. Noninverting Differential Input Overload

Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ ,  $V_{REF} = V_S / 2$ , and  $V_{IN+} = 12\text{ V}$  (unless otherwise noted)

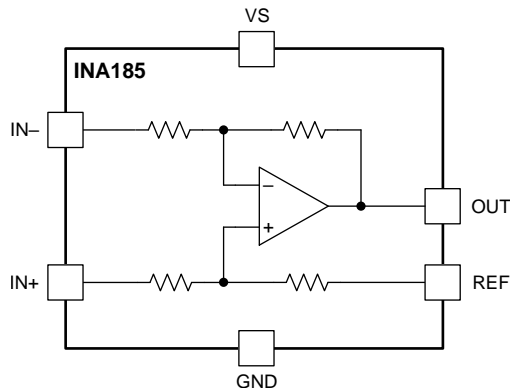


## 7 Detailed Description

### 7.1 Overview

The INA185 is a 26-V common-mode current-sensing amplifier used in both low-side and high-side configurations. This specially-designed, current-sensing amplifier accurately measures voltages developed across current-sensing resistors on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 26 V, and the device can be powered from supply voltages as low as 2.7 V.

### 7.2 Functional Block Diagrams



### 7.3 Feature Description

#### 7.3.1 High Bandwidth and Slew Rate

The INA185 supports small-signal bandwidths as high as 350 kHz, and large-signal slew rates of 2 V/μs. The ability to detect rapid changes in the sensed current, as well as the ability to quickly slew the output, make the INA185 a good choice for applications that require a quick response to input current changes. One application that requires high bandwidth and slew rate is low-side motor control, where the ability to follow rapid changing current in the motor allows for more accurate control over a wider operating range. Another application that requires higher bandwidth and slew rates is system fault detection, where the INA185 is used with an external comparator and a reference to quickly detect when the sensed current is out of range.

#### 7.3.2 Bidirectional Current Monitoring

The INA185 senses current flow through a sense resistor in both directions. The bidirectional current-sensing capability is achieved by applying a voltage at the REF pin to offset the output voltage. A positive differential voltage sensed at the inputs results in an output voltage that is greater than the applied reference voltage. Likewise, a negative differential voltage at the inputs results in output voltage that is less than the applied reference voltage. The output voltage of the current-sense amplifier is shown in [公式 1](#).

$$V_{\text{OUT}} = (I_{\text{LOAD}} \times R_{\text{SENSE}} \times \text{GAIN}) + V_{\text{REF}}$$

where

- $I_{\text{LOAD}}$  is the load current to be monitored.
- $R_{\text{SENSE}}$  is the current-sense resistor.
- GAIN is the gain option of the selected device.
- $V_{\text{REF}}$  is the voltage applied to the REF pin.

(1)

## Feature Description (接下页)

### 7.3.3 Wide Input Common-Mode Voltage Range

The INA185 supports input common-mode voltages from  $-0.2\text{ V}$  to  $+26\text{ V}$ . Because of the internal topology, the common-mode range is not restricted by the power-supply voltage ( $V_S$ ) as long as  $V_S$  stays within the operational range of  $2.7\text{ V}$  to  $5.5\text{ V}$ . The ability to operate with common-mode voltages greater or less than  $V_S$  allows the INA185 to be used in high-side, as well as low-side, current-sensing applications, as shown in 图 34.

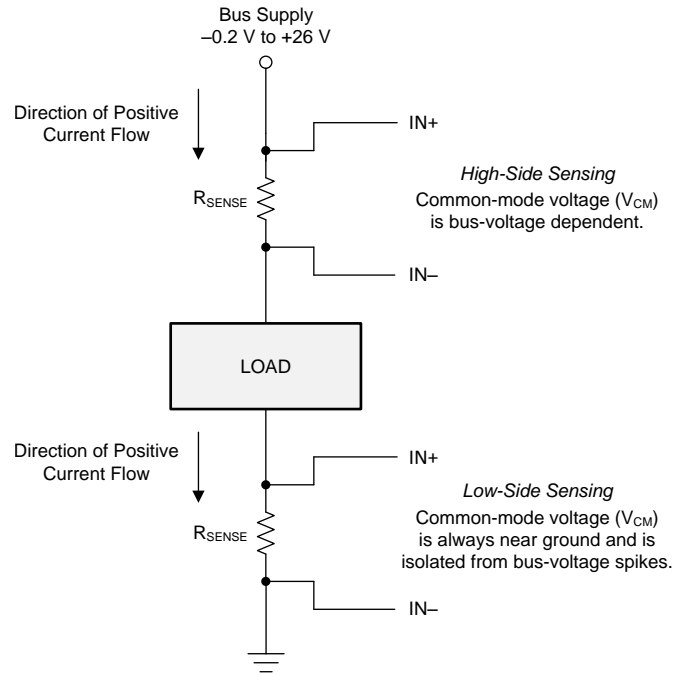


图 34. High-Side and Low-Side Sensing Connections

### 7.3.4 Precise Low-Side Current Sensing

When used in low-side current sensing applications, the offset voltage of the INA185 is within  $\pm 55\text{ }\mu\text{V}$  for A2, A3 and A4 devices. The low offset performance of the INA185 has two main benefits. First, the low offset allows these devices to be used in applications that must measure current over a wide dynamic range. In this case, the low offset improves the accuracy when the sensed currents are on the low end of the measurement range. The other advantage of low offset is the ability to sense lower voltage drop across the sense resistor accurately, thus allowing a lower-value shunt resistor. Lower-value shunt resistors reduce power loss in the current sense circuit, and help improve the power efficiency of the end application.

The gain error of the INA185 is specified to be within 0.2% of the actual value for A1, A2, and A3 devices. As the sensed voltage becomes much larger than the offset voltage, this voltage becomes the dominant source of error in the current sense measurement.

### 7.3.5 Rail-to-Rail Output Swing

The INA185 allows linear current sensing operation with the output close to the supply rail and GND. The maximum specified output swing to the positive rail is  $25\text{ mV}$ , and the maximum specified output swing to GND is only  $3.5\text{ mV}$ . In order to compare the output swing of the INA185 to an equivalent operational amplifier (op amp), the inputs are overdriven to approximate the open-loop condition specified in many op amp data sheets. The current-sense amplifier is a closed-loop system; therefore, the output swing to GND can be limited by the offset voltage and amplifier gain during unidirectional operation ( $V_{REF} = 0\text{ V}$ ) when there is zero current flowing through the sense resistor. To define the maximum output voltage under the zero current condition, the INA185 [Electrical Characteristics](#) table specifies a maximum output voltage of  $6\text{ mV}$  for the A1 device, and  $12\text{ mV}$  for all other devices.

## 7.4 Device Functional Modes

### 7.4.1 Normal Mode

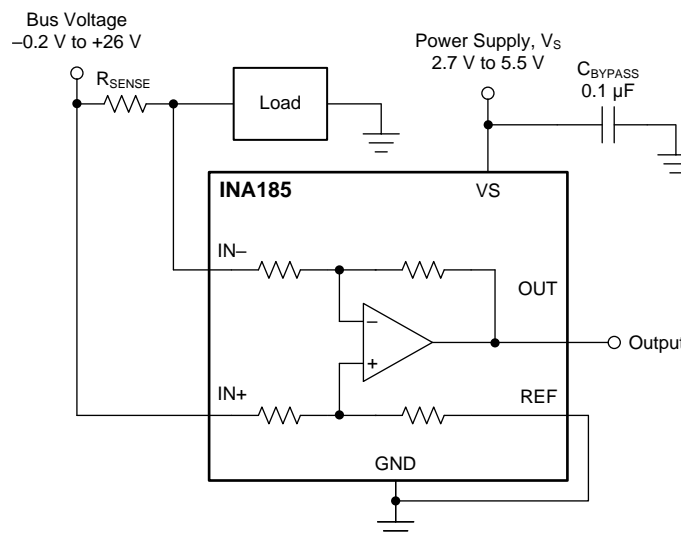
The INA185 is in normal operation when the following conditions are met:

- The power supply voltage ( $V_S$ ) is between 2.7 V and 5.5 V.
- The common-mode voltage ( $V_{CM}$ ) is within the specified range of  $-0.2$  V to  $+26$  V.
- The maximum differential input signal times gain plus  $V_{REF}$  is less than  $V_S$  minus the output voltage swing to  $V_S$ .
- The minimum differential input signal times gain plus  $V_{REF}$  is greater than the swing to GND (see the [Rail-to-Rail Output Swing](#) section).

During normal operation, these devices produce an output voltage that is the *gained-up* representation of the difference voltage from  $IN+$  to  $IN-$  plus the reference voltage at  $V_{REF}$ .

### 7.4.2 Unidirectional Mode

This device is capable of monitoring current flowing in one direction (unidirectional) or in both directions (bidirectional) depending on how the REF pin is configured. The most common case is unidirectional, where the output is set to ground when no current is flowing by connecting the REF pin to ground, as shown in [图 35](#). When the current flows from the bus supply to the load, the input signal across  $IN+$  to  $IN-$  increases, and causes the output voltage at the OUT pin to increase.



**图 35. Unidirectional Application**

The linear range of the output stage is limited by how close the output voltage can approach ground under zero input conditions. In unidirectional applications where measuring very low input currents is desirable, bias the REF pin to a convenient value above 50 mV to get the output into the linear range of the device. To limit common-mode rejection errors, buffer the reference voltage connected to the REF pin.

A less-frequently used output biasing method is to connect the REF pin to the power-supply voltage,  $V_S$ . This method results in the output voltage saturating at 25 mV less than the supply voltage when no differential input signal is present. This method is similar to the output saturated low condition with no input signal when the REF pin is connected to ground. The output voltage in this configuration only responds to negative currents that develop negative differential input voltage relative to the device  $IN-$  pin. Under these conditions, when the differential input signal increases negatively, the output voltage moves downward from the saturated supply voltage. The voltage applied to the REF pin must not exceed  $V_S$ .

## Device Functional Modes (接下页)

### 7.4.3 Bidirectional Mode

The INA185 is a bidirectional current-sense amplifier capable of measuring currents through a resistive shunt in two directions. This bidirectional monitoring is common in applications that include charging and discharging operations where the current flowing through the resistor can change directions.

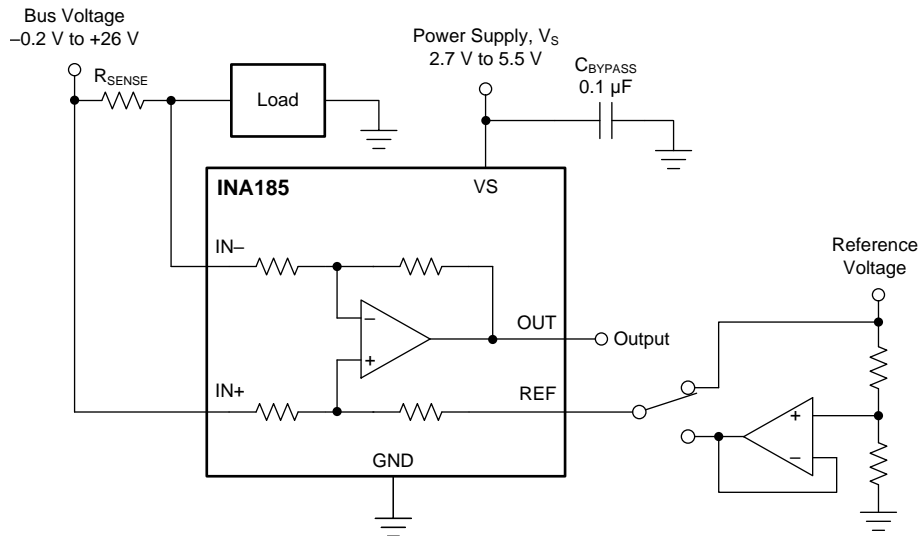


图 36. Bidirectional Application

The ability to measure this current flowing in both directions is enabled by applying a voltage to the REF pin, as shown in 图 36. The voltage applied to REF ( $V_{REF}$ ) sets the output state that corresponds to the zero-input level state. The output then responds by increasing above  $V_{REF}$  for positive differential signals (relative to the IN- pin) and responds by decreasing below  $V_{REF}$  for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to  $V_S$ . For bidirectional applications,  $V_{REF}$  is typically set at mid-scale for equal signal range in both current directions. In some cases, however,  $V_{REF}$  is set at a voltage other than midscale when the bidirectional current and corresponding output signal do not need to be symmetrical.

### 7.4.4 Input Differential Overload

If the differential input voltage ( $V_{IN+} - V_{IN-}$ ) times gain plus the reference voltage exceeds the voltage swing specification, the INA185 drives the output as close as possible to the positive supply or ground, and does not provide accurate measurement of the differential input voltage. If this input overload occurs during normal circuit operation, then reduce the value of the shunt resistor or use a lower-gain version with the chosen sense resistor to avoid this mode of operation. If a differential overload occurs in a fault event, then the output of the INA185 returns to the expected value approximately 20 µs after the fault condition is removed.

## Device Functional Modes (接下页)

### 7.4.5 Shutdown Mode

Although the INA185 does not have a shutdown pin, the low power consumption of these devices allows the output of a logic gate or transistor switch to power the INA185. This gate or switch turns on and off the INA185 power-supply quiescent current.

However, in current shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the simplified schematic of the INA185 in shutdown mode, as shown in 图 37.

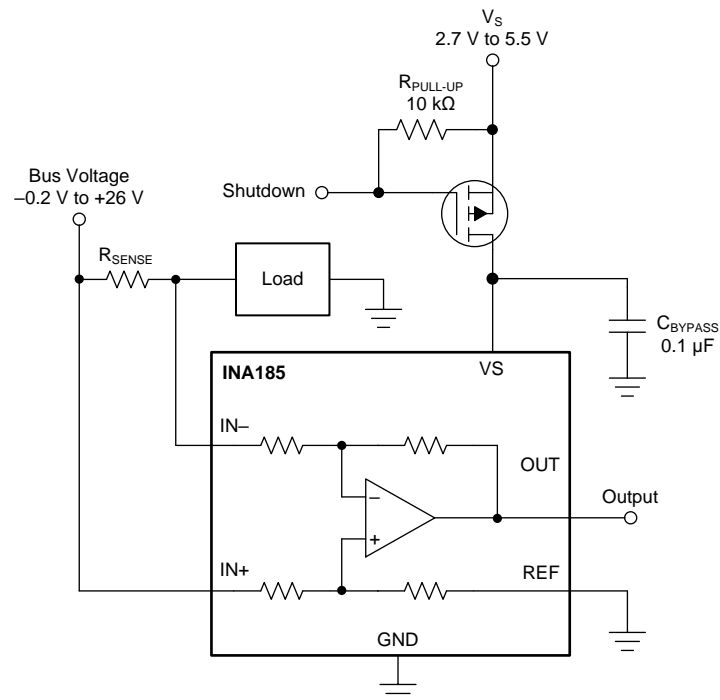


图 37. Basic Circuit to Shut Down the INA185 With a Grounded Reference

There is typically more than 500 kΩ of impedance (from the combination of 500-kΩ feedback and input gain set resistors) from each input of the INA185 to the OUT pin and to the REF pin. The amount of current flowing through these pins depends on the voltage at the connection. For example, if the REF pin is grounded, the calculation of the effect of the 500 kΩ impedance from the shunt to ground is straightforward. However, if the reference is powered while the INA185 is in shutdown mode, instead of assuming 500 kΩ to ground, assume 500 kΩ to the reference voltage.

Regarding the 500-kΩ path to the output pin, the output stage of a disabled INA185 does constitute a good path to ground. Consequently, this current is directly proportional to a shunt common-mode voltage present across a 500-kΩ resistor.

As a final note, as long as the shunt common-mode voltage is greater than  $V_S$  when the device is powered up, there is an additional and well-matched 55-μA typical current that flows in each of the inputs. If less than  $V_S$ , the common-mode input currents are negligible, and the only current effects are the result of the 500-kΩ resistors.



## 8 Application and Implementation

### 注

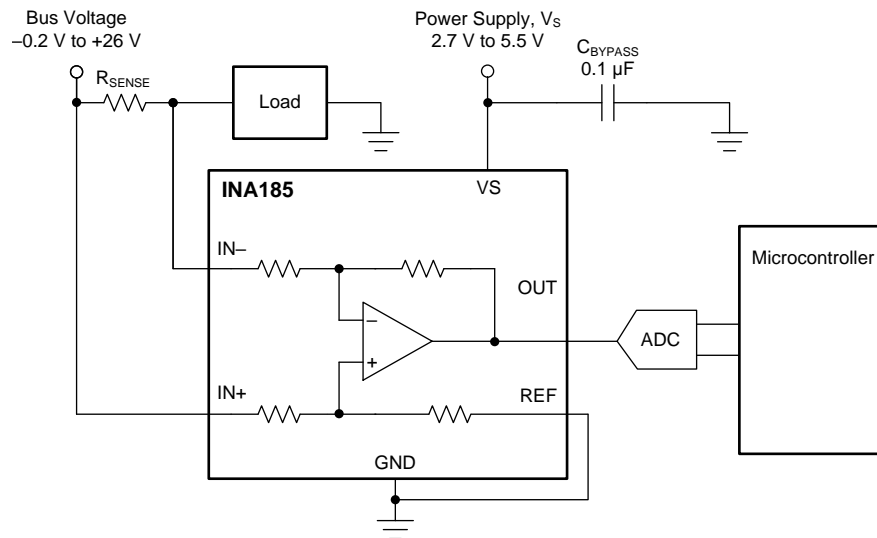
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The INA185 amplifies the voltage developed across a current-sensing resistor as current flows through the resistor to the load or ground. The ability to drive the reference pin to adjust the functionality of the output signal offers multiple configurations, as discussed in previous sections.

#### 8.1.1 Basic Connections

图 38 shows the basic connections of the INA185. Connect the input pins (IN+ and IN-) as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistor.



NOTE: To help eliminate ground offset errors between the device and the analog-to-digital converter (ADC), connect the REF pin to the ADC reference input and then to ground. For best performance, use an RC filter between the output of the INA185 and the ADC. See the [Closed-Loop Analysis of Load-Induced Amplifier Stability Issues Using ZOUT](#) section for more details.

图 38. Basic Connections for the INA185

A power-supply bypass capacitor of at least 0.1 μF is required for proper operation. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

## Application Information (接下页)

### 8.1.2 R<sub>SENSE</sub> and Device Gain Selection

Maximize the accuracy of the INA185 by choosing a current-sense resistor that is as large as possible. A large sense resistor maximizes the differential input signal for a given amount of current flow and reduces the error contribution of the offset voltage. However, there are practical limits as to how large the current-sense resistor can be in a given application. The INA185 has a typical input bias current of 75  $\mu\text{A}$  for each input when operated at a 12-V common-mode voltage input. When large current-sense resistors are used, these bias currents cause increased offset error and reduced common-mode rejection. Therefore, using current-sense resistors larger than a few ohms is generally not recommended for applications that require current-monitoring accuracy. Another common restriction on the value of the current-sense resistor is the maximum allowable power dissipation that is budgeted for the resistor. 公式 2 gives the maximum value for the current sense resistor for a given power dissipation budget:

$$R_{\text{SENSE}} < \frac{PD_{\text{MAX}}}{I_{\text{MAX}}^2}$$

where:

- $PD_{\text{MAX}}$  is the maximum allowable power dissipation in  $R_{\text{SENSE}}$ .
- $I_{\text{MAX}}$  is the maximum current that will flow through  $R_{\text{SENSE}}$ .

(2)

An additional limitation on the size of the current-sense resistor and device gain is due to the power-supply voltage,  $V_S$ , and device swing to rail limitations. In order to make sure that the current-sense signal is properly passed to the output, both positive and negative output swing limitations must be examined. 公式 3 provides the maximum values of  $R_{\text{SENSE}}$  and GAIN to keep the device from hitting the positive swing limitation.

$$I_{\text{MAX}} \times R_{\text{SENSE}} \times \text{GAIN} < V_{\text{SP}} - V_{\text{REF}}$$

where:

- $I_{\text{MAX}}$  is the maximum current that will flow through  $R_{\text{SENSE}}$ .
- GAIN is the gain of the current sense-amplifier.
- $V_{\text{SP}}$  is the positive output swing as specified in the data sheet.
- $V_{\text{REF}}$  is the externally applied voltage on the REF pin.

(3)

To avoid positive output swing limitations when selecting the value of  $R_{\text{SENSE}}$ , there is always a trade-off between the value of the sense resistor and the gain of the device under consideration. If the sense resistor selected for the maximum power dissipation is too large, then it is possible to select a lower-gain device in order to avoid positive swing limitations.

The negative swing limitation places a limit on how small of a sense resistor can be used in a given application. 公式 4 provides the limit on the minimum size of the sense resistor.

$$I_{\text{MIN}} \times R_{\text{SENSE}} \times \text{GAIN} > V_{\text{SN}} - V_{\text{REF}}$$

where:

- $I_{\text{MIN}}$  is the minimum current that will flow through  $R_{\text{SENSE}}$ .
- GAIN is the gain of the current sense amplifier.
- $V_{\text{SN}}$  is the negative output swing of the device (see [Rail-to-Rail Output Swing](#)).
- $V_{\text{REF}}$  is the externally applied voltage on the REF pin.

(4)

In addition to adjusting the offset and gain, the voltage applied to the REF pin can be slightly increased to avoid negative swing limitations.

## Application Information (接下页)

### 8.1.3 Signal Filtering

Provided that the INA185 output is connected to a high impedance input, the best location to filter is at the device output using a simple RC network from OUT to GND. Filtering at the output attenuates high-frequency disturbances in the common-mode voltage, differential input signal, and INA185 power-supply voltage. If filtering at the output is not possible, or filtering of only the differential input signal is required, then apply a filter at the input pins of the device. 图 39 provides an example of how a filter can be used on the input pins of the device.

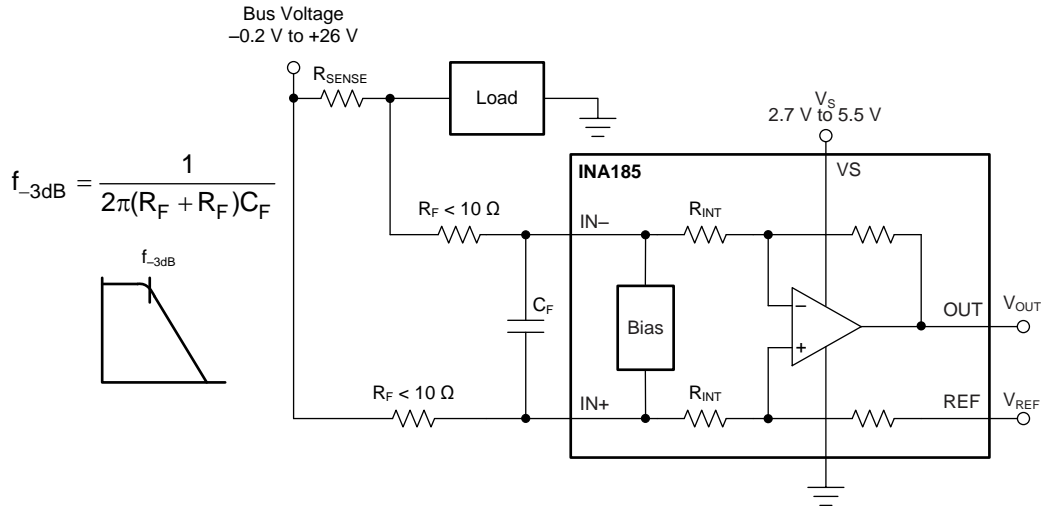


图 39. Filter at Input Pins

The addition of external series resistance creates an additional error in the measurement; therefore, the value of these series resistors must be kept to 10 Ω (or less, if possible) to reduce impact to accuracy. The internal bias network shown in 图 39 present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed across the shunt resistor. This error results in a voltage at the device input pins that is different than the voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. The amount of error these external filter resistors add to the measurement can be calculated using 公式 6, where the gain error factor is calculated using 公式 5.

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance ( $R_F$ ) value as well as the internal input resistor  $R_{INT}$ , as shown in 图 39. The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. Calculate the expected deviation from the shunt voltage to what is measured at the device input pins is given using 公式 5:

$$\text{Gain Error Factor} = \frac{1250 \times R_{INT}}{(1250 \times R_F) + (1250 \times R_{INT}) + (R_F \times R_{INT})}$$

where:

- $R_{INT}$  is the internal input resistor.
- $R_F$  is the external series resistance.

(5)

## Application Information (接下页)

With the adjustment factor from 公式 5, including the device internal input resistance, this factor varies with each gain version, as shown in 表 1. Each individual device gain error factor is shown in 表 2.

**表 1. Input Resistance**

PRODUCT	GAIN	R <sub>INT</sub> (kΩ)
INA185A1	20	25
INA185A2	50	10
INA185A3	100	5
INA185A4	200	2.5

**表 2. Device Gain Error Factor**

PRODUCT	SIMPLIFIED GAIN ERROR FACTOR
INA185A1	$\frac{25000}{(21 \times R_F) + 25000}$
INA185A2	$\frac{10000}{(9 \times R_F) + 10000}$
INA185A3	$\frac{1000}{R_F + 1000}$
INA185A4	$\frac{2500}{(3 \times R_F) + 2500}$

The gain error that can be expected from the addition of the external series resistors can then be calculated based on 公式 6:

$$\text{Gain Error (\%)} = 100 - (100 \times \text{Gain Error Factor}) \quad (6)$$

For example, using an INA185A2 and the corresponding gain error equation from 表 2, a series resistance of 10 Ω results in a gain error factor of 0.991. The corresponding gain error is then calculated using 公式 6, resulting in an additional gain error of approximately 0.89% solely because of the external 10-Ω series resistors.

## 8.2 Typical Application

One application for the INA185 is to monitor bidirectional currents. Bidirectional currents are present in systems that have to monitor currents in both directions; common examples are monitoring the charging and discharging of batteries and bidirectional current monitoring in motor control. The device configuration for bidirectional current monitoring is shown in 图 40. Applying stable REF pin voltage closer to the middle of device supply voltage allows both positive- and negative-current monitoring, as shown in this configuration. Configure the INA185 to monitor unidirectional currents by grounding the REF pin.

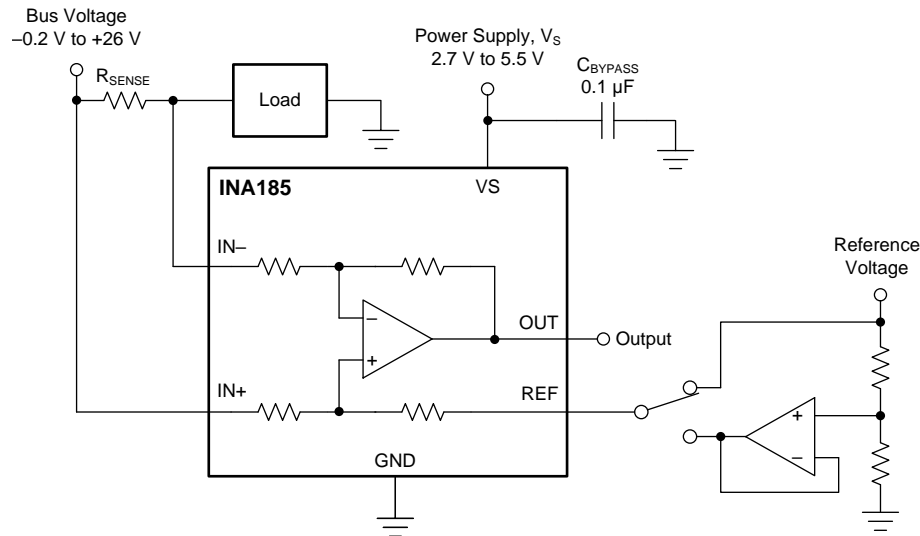


图 40. Measuring Bidirectional Current

### 8.2.1 Design Requirements

The design requirements for the circuit shown in 图 40, are listed in 表 3

表 3. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Power-supply voltage, $V_S$	5 V
Bus supply rail, $V_{CM}$	12 V
$R_{SENSE}$ power loss	< 450 mW
Maximum sense current, $I_{MAX}$	$\pm 20$ A
Current sensing error	Less than 1% at maximum current, $T_J = 25^\circ\text{C}$
Small-signal bandwidth	> 100 kHz

### 8.2.2 Detailed Design Procedure

The maximum value of the current sense resistor is calculated based on the maximum power loss requirement. By applying 公式 2, the maximum value of the current-sense resistor is calculated to be 1.125 m $\Omega$ . This is the maximum value for sense resistor  $R_{SENSE}$ ; therefore, select  $R_{SENSE}$  to be 1 m $\Omega$  because it is the closest standard resistor value that meets the power-loss requirement.

The next step is to select the appropriate gain and reduce  $R_{SENSE}$ , if needed, to keep the output signal swing within the  $V_S$  range. The design requirements call for bidirectional current monitoring; therefore, a voltage between 0 and  $V_S$  must be applied to the REF pin. The bidirectional currents monitored are symmetric around 0 (that is,  $\pm 20$  A); therefore, the ideal voltage to apply to  $V_{REF}$  is  $V_S / 2$  or 2.5 V. If the positive current is greater than the negative current, using a lower voltage on  $V_{REF}$  has the benefit of maximizing the output swing for the given range of expected currents. Using 公式 3, and given that  $I_{MAX} = 20$  A,  $R_{SENSE} = 1$  m $\Omega$ , and  $V_{REF} = 2.5$  V,

the maximum current-sense gain calculated to avoid the positive swing-to-rail limitations on the output is 122.5. Likewise, using 公式 4 for the negative-swing limitation results in a maximum gain of 124.75. Selecting the gain-of-100 device maximizes the output range while staying within the output swing range. If the maximum calculated gains are slightly less than 100, the value of the current-sense resistor can be reduced to keep the output from hitting the output-swing limitations.

To calculate the accuracy at peak current, the two factors that must be determined are the gain error and the offset error. The gain error of the INA185A3 is specified to be a maximum of 0.2%. The error due to the offset is constant, and is specified to be 130 μV (maximum) for the conditions where  $V_{CM} = 12\text{ V}$  and  $V_S = 5\text{ V}$ . Using 公式 7, the percentage error contribution of the offset voltage is calculated to be 0.65%, with total offset error = 130 μV,  $R_{SENSE} = 1\text{ m}\Omega$ , and  $I_{SENSE} = 20\text{ A}$ .

$$\text{Total Offset Error (\%)} = \frac{\text{Total Offset Error (V)}}{I_{SENSE} \times R_{SENSE}} \times 100\% \tag{7}$$

One method of calculating the total error is to add the gain error to the percentage contribution of the offset error. However, in this case, the gain error and the offset error do not have an influence or correlation to each other. A more statistically accurate method of calculating the total error is to use the RSS sum of the errors, as shown in 公式 8:

$$\text{Total Error (\%)} = \sqrt{\text{Total Gain Error (\%)}^2 + \text{Total Offset Error (\%)}^2} \tag{8}$$

After applying 公式 8, the total current sense error at maximum current is calculated to be 0.68%, which is less than the design example requirement of 1%.

The INA185A3 (gain = 100) also has a bandwidth of 150 kHz that meets the small-signal bandwidth requirement of 100 kHz. If higher bandwidth is required, lower-gain devices can be used at the expense of either reduced output voltage range or an increased value of  $R_{SENSE}$ .

### 8.2.3 Application Curve

An example output response of a bidirectional configuration is shown in 图 41. With the REF pin connected to a reference voltage (2.5 V in this case), the output voltage is biased upwards by this reference level. The output rises above the reference voltage for positive differential input signals, and falls below the reference voltage for negative differential input signals.

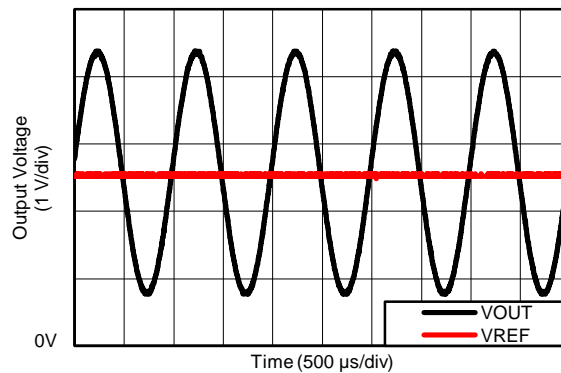


图 41. Bidirectional Application Output Response

## 9 Power Supply Recommendations

The input circuitry of the INA185 allows for accurate measurements beyond the power-supply voltage,  $V_S$ . For example,  $V_S$  can be 5 V, whereas the bus supply voltage at IN+ and IN– can be as high as 26 V. However, the output voltage range of the OUT pin is limited by the voltages on the VS pin. The INA185 also withstands the full differential input signal range up to 26 V at the IN+ and IN– input pins, regardless of whether or not the device has power applied at the VS pin.

### 9.1 Common-Mode Transients Greater Than 26 V

With a small amount of additional circuitry, the INA185 can be used in circuits subject to transients higher than 26 V, such as automotive applications. Use only Zener diodes or Zener-type transient absorbers (sometimes referred to as *transzorb*s)—any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors as a working impedance for the Zener diode; see [Figure 42](#). Keep these resistors as small as possible; most often, around 10  $\Omega$ . Larger values can be used with an effect on gain that is discussed in the [Signal Filtering](#) section. This circuit limits only short-term transients; therefore, many applications are satisfied with a 10- $\Omega$  resistor along with conventional Zener diodes of the lowest acceptable power rating. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523.

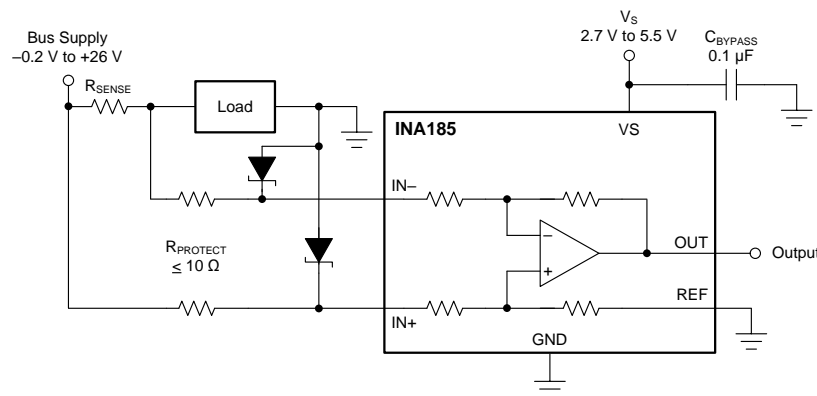


图 42. Transient Protection Using Dual Zener Diodes

In the event that low-power Zener diodes do not have sufficient transient absorption capability, a higher-power transzorb must be used. The most package-efficient solution involves using a single transzorb and back-to-back diodes between the device inputs, as shown in [Figure 43](#). The most space-efficient solutions are dual, series-connected diodes in a single SOT-523 or SOD-523 package. In either of the examples shown in [Figure 42](#) and [Figure 43](#), the total board area required by the INA185 with all protective components is less than that of an SO-8 package, and only slightly greater than that of an MSOP-8 package.

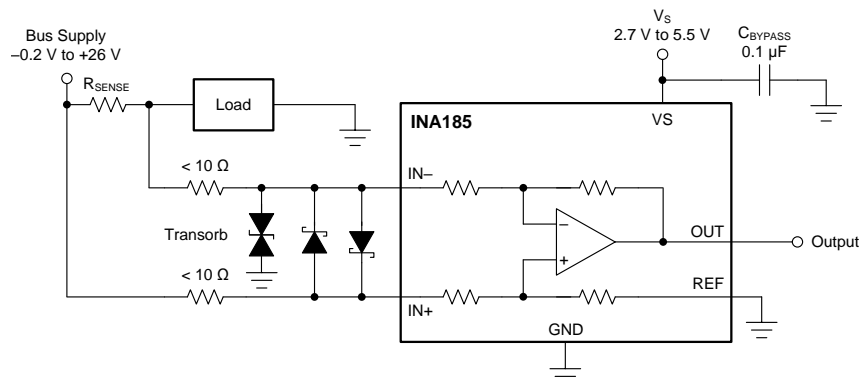


图 43. Transient Protection Using a Single Transzorb and Input Clamps

For more information, see [Current Shunt Monitor With Transient Robustness Reference Design](#).

## 10 Layout

### 10.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique makes sure that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.
- Place the power-supply bypass capacitor as close as possible to the device power supply and ground pins. The recommended value of this bypass capacitor is 0.1  $\mu\text{F}$ . Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.
- When routing the connections from the current sense resistor to the device, keep the trace lengths as close as possible in order to minimize any impedance mismatch..

### 10.2 Layout Example

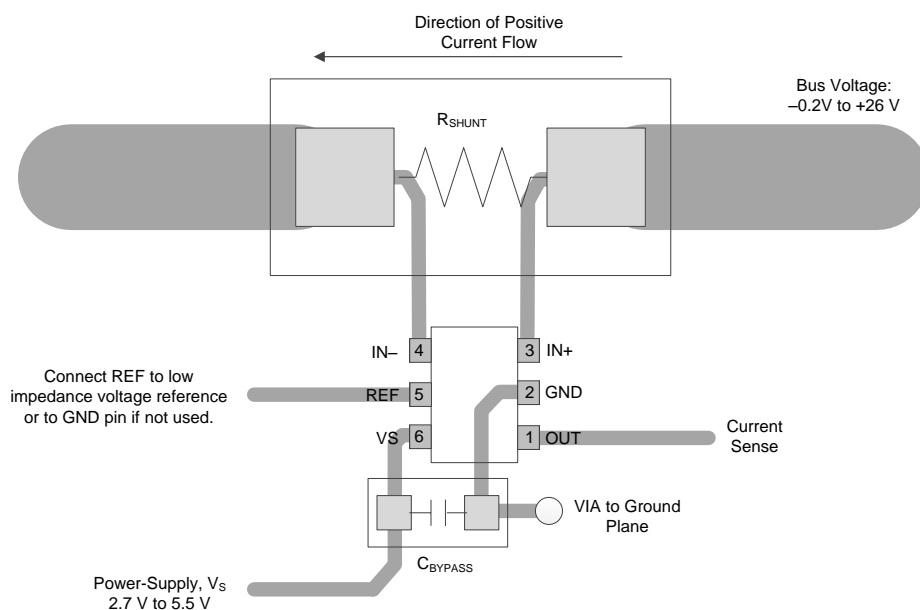


图 44. Recommended Layout



## 11 器件和文档支持

### 11.1 器件支持

#### 11.1.1 开发支持

《具有瞬态稳定性的电流分流监控器参考设计》

### 11.2 文档支持

#### 11.2.1 相关文档

请参阅如下相关文档：德州仪器 (TI)，《[INA185EVM 用户指南](#)》

### 11.3 接收文档更新通知

要接收文档更新通知，请导航至 [TI.com.cn](http://TI.com.cn) 上的器件产品文件夹。单击右上角的 [通知我](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 11.7 术语表

**SLYZ022** — TI 术语表。

这份术语表列出并解释术语、缩写和定义。

## 12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA185A1IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A1IDRLT	SOT-5X3	DRL	6	250	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A2IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A2IDRLT	SOT-5X3	DRL	6	250	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A3IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A3IDRLT	SOT-5X3	DRL	6	250	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A4IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A4IDRLT	SOT-5X3	DRL	6	250	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA185A1IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A1IDRLT	SOT-5X3	DRL	6	250	183.0	183.0	20.0
INA185A2IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A2IDRLT	SOT-5X3	DRL	6	250	183.0	183.0	20.0
INA185A3IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A3IDRLT	SOT-5X3	DRL	6	250	183.0	183.0	20.0
INA185A4IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A4IDRLT	SOT-5X3	DRL	6	250	183.0	183.0	20.0

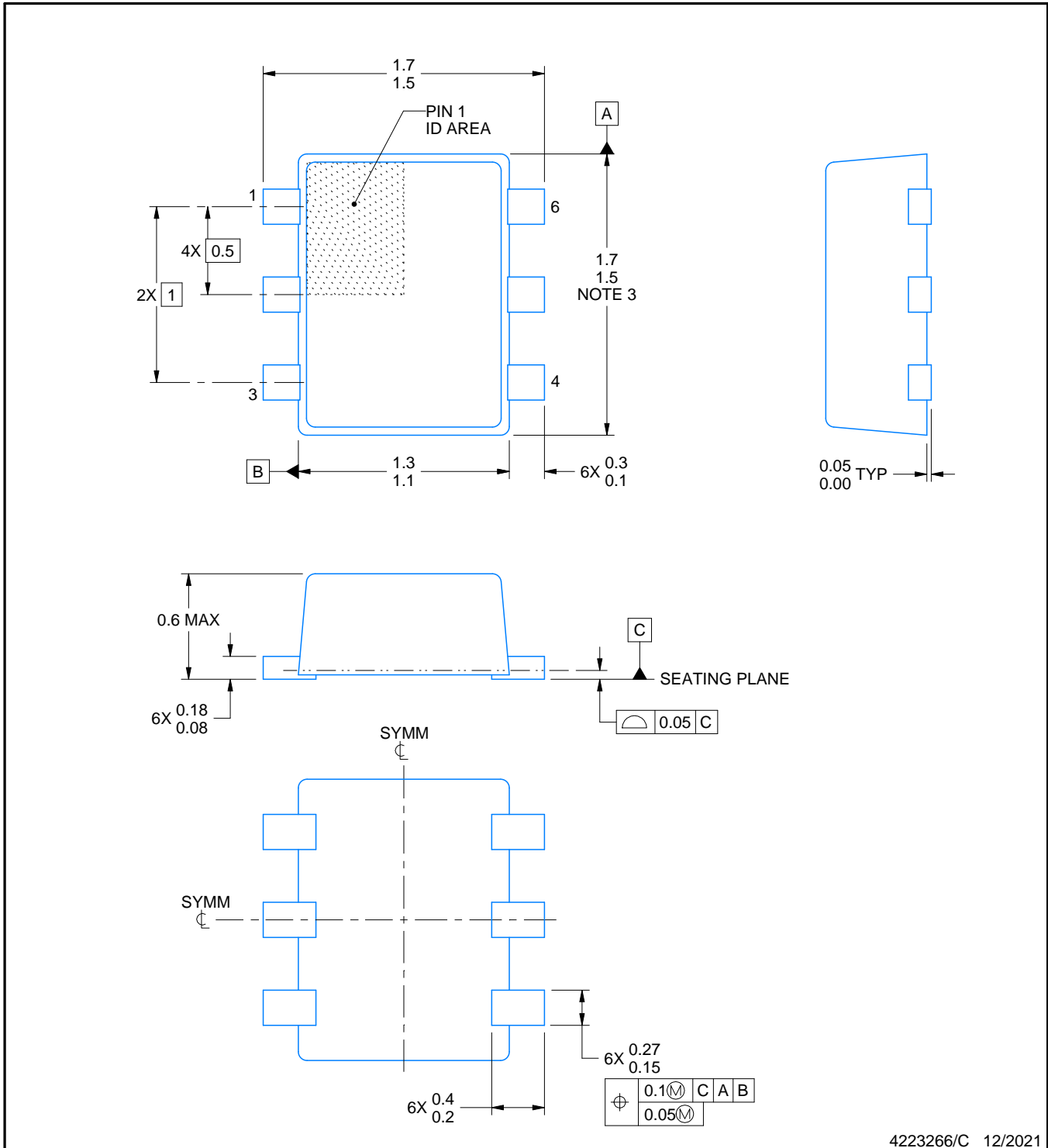
# DRL0006A



# PACKAGE OUTLINE

## SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



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### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD

# EXAMPLE BOARD LAYOUT

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE  
SCALE:30X



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NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

# EXAMPLE STENCIL DESIGN

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:30X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## 重要声明和免责声明

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